AXP1T34

Dual supply translating buffer

Rev. 1 — 1 December 2023

Product data sheet

1. General description

The AXP1T34 is a single bit, dual supply translating buffer. It features one input (A), an output (Y) and dual supply pins ($V_{\rm CCI}$ and $V_{\rm CCO}$). Both $V_{\rm CCI}$ and $V_{\rm CCO}$ can be supplied at any voltage between 0.9 V and 5.5 V making the device suitable for translating between any voltage nodes specified (1.2 V, 1.5 V, 1.8 V, 2.5 V, 3.3 V and 5.0 V). No power supply sequencing is required and output glitches during power supply transitions are prevented using patented circuitry. As a result, glitches will not appear on the outputs for supply transitions during power-up/down between 20 mV/ μ s and 5.5 V/s

The input is referenced to V_{CCI} and the output is referenced to V_{CCO} . Schmitt-trigger action at the input makes the circuit tolerant of slower input rise and fall times.

This device ensures low static and dynamic power consumption across the entire supply range and is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down. In suspend mode when either V_{CCI} or V_{CCO} are at GND level the output is in the high-impedance OFF-state

2. Features and benefits

- Wide supply voltage range:
 - V_{CCI}: 0.9 V to 5.5 V
 - V_{CCO}: 0.9 V to 5.5 V
- Low input capacitance; C_I = 1.5 pF (typical)
- Low output capacitance; C_O = 3.8 pF (typical)
- Low dynamic power consumption; C_{PD} = 0.4 pF at V_{CCI} = 1.2 V (typical)
- Low dynamic power consumption; C_{PD} = 11 pF at V_{CCO} = 5 V (typical)
- Low static power consumption; I_{CCI} = 0.1 μA (25 °C maximum)
- Low static power consumption; I_{CCO} = 1.0 μA (25 °C maximum)
- High noise immunity
- Complies with JEDEC standard:
 - JESD8-12 (1.1 V to 1.3 V; A input)
 - JESD8-11 (1.4 V to 1.6 V)
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8C (2.7 V to 3.6 V)
 - JESD12-6 (4.5 V to 5.5 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Latch-up performance exceeds 100 mA per JESD78D Class II
- Inputs accept voltages up to 5.5 V
- Low noise overshoot and undershoot < 10% of V_{CCO}
- I_{OFF} circuitry provides partial power-down mode operation
- Multiple package options
- Specified from -40 °C to +125 °C



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3. Ordering information

Table 1. Ordering information

Type number	Package	Package							
	Temperature range	Name	Description	Version					
AXP1T34GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1					
AXP1T34GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886					
AXP1T34GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202					
AXP1T34GX	-40 °C to +125 °C	X2SON5	plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.32 mm	SOT1226-3					

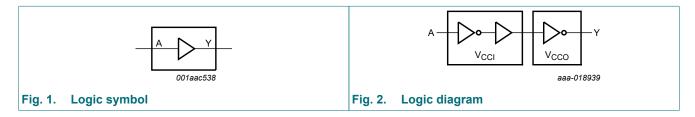
4. Marking

Table 2. Marking

Type number	Marking code[1]
AXP1T34GW	r3
AXP1T34GM	r3
AXP1T34GS	r3
AXP1T34GX	r3

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

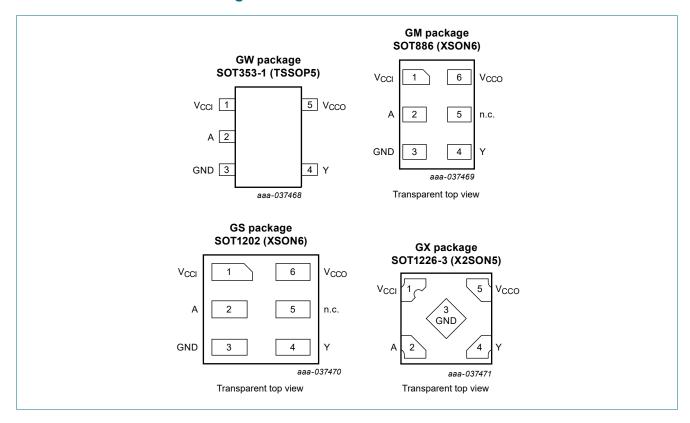
5. Functional diagram



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6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description

Symbol	Pin	Pin				
	TSSOP5 and X2SON5	XSON6				
V _{CCI}	1	1	input supply voltage			
A	2	2	data input A			
GND	3	3	ground (0 V)			
Υ	4	4	data output Y			
n.c.	-	5	not connected			
V _{CCO}	5	6	output supply voltage			

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7. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$

Supply voltage		Input	Output
V _{CCO} V _{CCO}		A	Υ
0.9 V to 5.5 V	0.9 V to 5.5 V	L	L
0.9 V to 5.5 V	0.9 V to 5.5 V	Н	Н
GND[1]	0.9 V to 5.5 V	X	Z
0.9 V to 5.5 V	GND[1]	X	Z
GND[1]	GND[1]	X	Z

^[1] If V_{CCI} or V_{CCO} is at GND level, the device goes into suspend mode.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CCI}	input supply voltage			-0.5	+6.5	V
V _{CCO}	output supply voltage			-0.5	+6.5	V
I _{IK}	input clamping current	V _I < 0 V		50	-	mA
V _I	input voltage		[1]	-0.5	+6.5	V
I _{OK}	output clamping current	V _O < 0 V		-50	-	mA
Vo	output voltage	Active mode	[1] [2]	-0.5	V _{CCO} + 0.5	V
		Suspend or 3-state mode	[1]	-0.5	+6.5	V
Io	output current	V _O = 0 V to V _{CCO}		-	±25	mA
Icc	supply current	I _{CCI} or I _{CCO} ; per V _{CC} pin		-	50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[3]	-	250	mW

The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SOT886 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

For SOT1202 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

For SOT1226-3 (X2SON5) package: Ptot derates linearly with 3.0 mW/K above 67 °C.

V_{CCO} + 0.5 V should not exceed 6.5 V.

For SOT353-1 (TSSOP5) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

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9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CCI}	input supply voltage		0.9	5.5	V
V _{CCO}	output supply voltage		0.9	5.5	V
VI	input voltage		0	5.5	V
Vo	output voltage	Active mode [1]	0	V _{cco}	V
		Power-down or 3-state mode	0	5.5	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise	$V_{CCI} = 0.9 \text{ V}$ [2]	-	20	ns/V
	and fall rate	V _{CCI} = 1.1 V to 1.3 V	-	20	ns/V
		V _{CCI} = 1.4 V to 1.95 V	-	20	ns/V
		V _{CCI} = 2.3 V to 2.7 V	-	20	ns/V
		V _{CCI} = 3.0 V to 3.6 V	-	10	ns/V
		V _{CCI} = 4.5 V to 5.5 V	-	8	ns/V

 V_{CCO} is the supply voltage associated with the output port. V_{CCI} is the supply voltage associated with the input port.

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10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions, unless otherwise specified; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	T,	_{amb} = 25 °	,C	T _{amb} = -40 °	C to +85 °C	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$		Unit
			Min	Тур	Max	Min	Max	Min	Max	
V _{IH}	HIGH-level	V _{CCI} = 0.9 V	0.7V _{CCI}	-	-	0.7V _{CCI}	-	0.7V _{CCI}	-	V
	input voltage	V _{CCI} = 1.1 V to 1.95 V	0.65V _{CCI}	-	-	0.65V _{CCI}	-	0.65V _{CCI}	-	V
		V _{CCI} = 2.3 V to 2.7 V	1.6	-	-	1.6	-	1.6	-	V
		V _{CCI} = 3.0 V to 3.6 V	2	-	-	2	-	2	-	V
		V _{CCI} = 4.5 V to 5.5 V	0.7V _{CCI}	-	-	0.7V _{CCI}	-	0.7V _{CCI}	-	V
V _{IL}	LOW-level	V _{CCI} = 0.9 V	-	-	0.3V _{CCI}	-	0.3V _{CCI}	-	0.3V _{CCI}	V
	input voltage	V _{CCI} = 1.1 V to 1.95 V	-	-	0.35V _{CCI}	-	0.35V _{CCI}	-	0.35V _{CCI}	V
		V _{CCI} = 2.3 V to 2.7 V	-	-	0.7	-	0.7	-	0.7	V
		V _{CCI} = 3.0 V to 3.6 V	-	-	0.8	-	0.8	-	0.8	V
		V _{CCI} = 4.5 V to 5.5 V	-	-	0.3V _{CCI}	-	0.3V _{CCI}	-	0.3V _{CCI}	V
V _{OH}	HIGH-level	$V_I = V_{IH};$								
	output voltage	I_{O} = -0.1 mA; V_{CCO} = 0.9 V to 5.5 V [1]	V _{CCO} -0.1	0.9	-	V _{CCO} -0.1	-	V _{CCO} -0.1	-	V
		I _O = -1.5 mA; V _{CCO} = 1.1 V	0.825	-	-	0.825	-	0.825	-	V
		I_{O} = -3 mA; V_{CCO} = 1.4 V	1.05	-	-	1.05	-	1.05	-	V
		I _O = -4.5 mA; V _{CCO} = 1.65 V	1.2	-	-	1.2	-	1.2	-	V
		I_{O} = -8 mA; V_{CCO} = 2.3 V	1.7	-	-	1.7	-	1.7	-	V
		I _O = -10 mA; V _{CCO} = 3.0 V	2.2	-	-	2.2	-	2.2	-	V
		I _O = -12 mA; V _{CCO} = 4.5 V	3.7	-	-	3.7	-	3.7	-	V

Symbol	Parameter	Conditions		Γ _{amb} = 25 °	,C	T _{amb} = -40	°C to +85 °C	T_{amb} = -40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
V _{OL}	LOW-level	$V_I = V_{IL};$								
	output voltage	I_{O} = 0.1 mA; V_{CCO} = 0.9 V to 5.5 V	1] -	0	0.1	-	0.1	-	0.1	V
		I _O = 1.5 mA; V _{CCO} = 1.1 V	-	-	0.275	-	0.275	-	0.275	V
		I _O = 3 mA; V _{CCO} = 1.4 V	-	-	0.35	-	0.35	-	0.35	V
		I _O = 4.5 mA; V _{CCO} = 1.65 V	-	-	0.45	-	0.7	-	0.7	V
		I _O = 8 mA; V _{CCO} = 2.3 V	-	-	0.7	-	0.8	-	0.8	V
		I _O = 10 mA; V _{CCO} = 3.0 V	-	-	0.8	-	0.8	-	0.8	V
		I _O = 12 mA; V _{CCO} = 4.5 V	-	-	0.8	-	0.8	-	0.8	V
I _I	input leakage current	V _I = 0 V to 5.5 V; V _{CCI} = 0.9 V to 5.5 V	-	-	±0.1	-	±0.5	-	±1	μΑ
I _{OZ}	OFF-state	1 1		-	±0.1	-	±0.5	-	±2	μΑ
	output current	suspend mode Y output; $V_O = 0 \text{ V or } V_{CCO}$; $V_{CCI} = 5.5 \text{ V}$; $V_{CCO} = 0 \text{ V}$	-	-	±0.1	-	±0.5	-	±2	μΑ
		suspend mode Y output; $V_O = 0 \text{ V or } V_{CCO}$; $V_{CCI} = 0 \text{ V}$; $V_{CCO} = 5.5 \text{ V}$	-	-	±0.1	-	±0.5	-	±2	μΑ
I _{OFF}	power-off	A input; V _I = 0 V to 5.5 V; V _{CCI} = 0 V; V _{CCO} = 0.9 V to 5.5 V	-	-	±0.1	-	±0.5	-	±2	μA
leakage current	_	Y output; V_I or V_O = 0 V to 5.5 V; V_{CCI} = 0.9 V to 5.5 V; V_{CCO} = 0 V	-	-	±0.1	-	±0.5	-	±2	μΑ
Δl _{OFF}	additional power-off	A input; $V_I = 0 \text{ V to } 5.5 \text{ V}$; $V_{CCI} = 0 \text{ V to } 0.1 \text{ V}$; $V_{CCO} = 0.9 \text{ V to } 5.5 \text{ V}$	-	-	±0.1	-	±0.5	-	±2	μΑ
	leakage current	Y output; V_I or V_O = 0 V to 5.5 V; V_{CCI} = 0.9 V to 5.5 V; V_{CCO} = 0 V to 0.1 V	-	-	±0.1	-	±0.5	-	±2	μΑ

^[1] Typical values for V_{OL} and V_{OH} are measured at V_{CCO} = 0.9 V

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Table 8. Static characteristics supply current

At recommended operating conditions, unless otherwise specified; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	T _{amb} :	= 25 °C	T _{amb} = -40 °	C to +85 °C	T _{amb} = -40 °	C to +125 °C	Unit
			Тур	Max	Min	Max	Min	Max	
I _{CCI}	input supply current	V _I = 0 V or V _{CCI} ; see <u>Table 8</u>							
		V_{CCI} , $V_{CCO} = 0.9 \text{ V to } 5.5 \text{ V}$ [1]	0.01	0.1	-	0.5	-	1	μA
		V _{CCI} = 5.5 V; V _{CCO} = 0 V	0.01	0.1	-	0.2	-	1	μA
		V _{CCI} = 0 V; V _{CCO} = 5.5 V	0.01	0.1	-	0.1	-	0.5	μA
I _{CCO}	output supply current	V _I = 0 V or V _{CCI} ; I _O = 0 A; see <u>Table 10</u>							
		V_{CCI} , $V_{CCO} = 0.9 \text{ V to } 5.5 \text{ V}$ [1]	0.125	1	-	1.2	-	1.5	μA
		V _{CCI} = 5.5 V; V _{CCO} = 0 V	0.01	0.1	-	0.2	-	0.5	μA
		V _{CCI} = 0 V; V _{CCO} = 5.5 V	0.01	0.6	-	0.8	-	1	μA
ΔI_{CCI}	additional input supply current	$V_I = V_{CCI} - 0.6 \text{ V}; I_O = 0 \text{ A}$							μA
		V_{CCI} , $V_{CCO} = 4.5 \text{ V to } 5.5 \text{ V}$ [2]	2	100	-	150	-	200	μA

^[1] Typical values are measured at $V_{CCI} = V_{CCO} = 1.2 \text{ V}$ [2] Typical values for ΔI_{CC} are measured at V_{CCI} , $V_{CCO} = 5 \text{ V}$

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Table 9. Typical input supply current (I_{CCI}) at Tamb = 25 °C

Voltages are referenced to GND (ground = 0 V).

V _{CCI}	V _{CCO}								Unit
	0 V	0.9 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	5.0 V	
0 V	10	10	10	10	10	10	10	10	nA
0.9 V	10	10	10	10	10	10	10	10	nA
1.2 V	10	10	10	10	10	10	10	10	nA
1.5 V	10	10	10	10	10	10	10	10	nA
1.8 V	10	10	10	10	10	10	10	10	nA
2.5 V	10	10	10	10	10	10	10	10	nA
3.3 V	10	10	10	10	10	10	10	10	nA
5 V	10	10	10	10	10	10	10	10	nA

Table 10. Typical output supply current (I_{CCO}) at Tamb = 25 °C

Voltages are referenced to GND (ground = 0 V).

V _{CCI}	V _{CCO}	V _{CCO}									
	0 V	0.9 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	5.0 V			
0 V	10	10	10	10	10	10	10	10	nA		
0.9 V	10	85	125	150	170	240	320	500	nA		
1.2 V	10	85	125	150	170	240	320	500	nA		
1.5 V	10	85	125	150	170	240	320	500	nA		
1.8 V	10	85	125	150	170	240	320	500	nA		
2.5 V	10	85	125	150	170	240	320	500	nA		
3.3 V	10	85	125	150	170	240	320	500	nA		
5 V	15	85	125	150	170	240	320	500	nA		

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11. Dynamic characteristics

Table 11. Typical dynamic characteristics at V_{CCI} = 0.9 V and T_{amb} = 25 °C

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 4; for waveforms see Fig. 3.

Symbol	Parameter	Conditions		V _{cco}						Unit
			0.9 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	5.0 V	
t _{pd}	propagation delay	A to Y	40	22	18.5	16.5	15	15	15	ns

^[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

Table 12. Typical dynamic characteristics at V_{CCO} = 0.9 V and T_{amb} = 25 °C

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 4; for waveforms see Fig. 3.

Symbol	Parameter	Conditions		V _{ccl}					Unit		
				0.9 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	5.0 V	
t _{pd}	propagation delay	A to Y	1]	40	33	32	31	31	31	32	ns

^[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

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Table 13. Typical dynamic characteristics at T_{amb} = 25 °C

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 4; for waveform see Fig. 3.

Symbol	Parameter	Conditions				V _{cco}				Unit
			0.9 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	5.0 V	
C _{PD}	power dissipation	$ f_i = 1 \text{ MHz; } V_I = \text{GND to } V_{\text{CCI}}; $								
	capacitance	input supply [2]								
		V _{CCI} = 0.9 V	0.4	0.4	0.4	0.4	0.4	0.4	0.4	pF
		V _{CCI} = 1.2 V	0.4	0.4	0.4	0.4	0.4	0.4	0.4	pF
		V _{CCI} = 1.5 V	0.4	0.4	0.4	0.4	0.4	0.4	0.4	pF
		V _{CCI} = 1.8 V	0.4	0.4	0.4	0.4	0.4	0.4	0.4	pF
		V _{CCI} = 2.5 V	0.5	0.5	0.5	0.5	0.5	0.5	0.5	pF
		V _{CCI} = 3.3 V	0.6	0.6	0.6	0.6	0.6	0.6	0.6	pF
		V _{CCI} = 5.0 V	0.9	0.9	0.9	0.9	0.9	0.9	0.9	pF
		output supply [3]								
		V _{CCI} = 0.9 V	9.4	9.4	9.4	9.5	9.7	10.3	12	pF
		V _{CCI} = 1.2 V	9.4	9.4	9.5	9.5	9.6	9.9	10.7	рF
		V _{CCI} = 1.5 V	9.4	9.4	9.5	9.5	9.7	9.9	10.4	pF
		V _{CCI} = 1.8 V	9.4	9.4	9.5	9.6	9.7	9.9	10.4	pF
		V _{CCI} = 2.5 V	9.5	9.5	9.6	9.6	9.8	10	10.4	pF
		V _{CCI} = 3.3 V	9.7	9.7	9.7	9.7	9.9	10.1	10.5	pF
		V _{CCI} = 5.0 V	10.1	10.1	10.1	10.2	10.3	10.4	10.8	pF
Cı	input capacitance	$V_I = 0 \text{ V or } V_{CCI}; V_{CCI} = 0 \text{ V to } 5.5 \text{ V}$	1.5	1.5	1.5	1.5	1.5	1.5	1.5	pF
Co	output $V_O = 0 \text{ V}; V_{CCO} = 0 \text{ V}$ capacitance					3.8				pF

^[1] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

[2] Power dissipated from input supply (V_{CCI})

P_D = C_{PD} x V_{CCI}² x f_i x N where:

C_{PD} = power dissipation capacitance of the input supply.

V_{CCI} = input supply voltage in V;

f_i = input frequency in MHz;

N = number of inputs switching;

[3] Power dissipated from output supply (V_{CCO})

 $P_D = (C_L + C_{PD}) \times V_{CCO}^2 \times f_o$ where:

C_L = load capacitance in pF;

 C_{PD} = power dissipation capacitance of the output supply.

V_{CCO} = output supply voltage in V;

f_o = output frequency in MHz;

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Table 14. Dynamic characteristics for temperature range -40 °C to +85 °C and -40 °C to +125 °C

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 4; for waveforms see Fig. 3.

Symbol	Parameter	Conditions		V _{CCO}										Unit	
			1.2 V	1.2 V ± 0.1 V		1.5 V ± 0.1 V		1.8 V ± 0.15 V		± 0.2 V	3.3 V ± 0.3 V		5.0 V ± 0.5 V		
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
Γ _{amb} = -4	10 °C to +85 °C					'						-		•	
t _{pd}	propagation	A to Y	[1]												T
	delay	V _{CCI} = 1.2 V ± 0.1 V	4.0	38	3.6	25	3.4	21	3.1	16	2.9	14.5	2.7	14.5	ns
		V _{CCI} = 1.5 V ± 0.1 V	3.5	33	3.0	21	2.8	16.5	2.6	12.5	2.4	10.5	2.2	9.8	ns
		V _{CCI} = 1.8 V ± 0.15 V	3.1	32	2.7	19	2.4	15	2.2	11	2.1	9.0	1.9	8.2	ns
		V _{CCI} = 2.5 V ± 0.2 V	2.8	31	2.4	17.5	2.1	13.5	1.9	9.1	1.7	7.5	1.6	6.6	ns
		V _{CCI} = 3.3 V ± 0.3 V	2.7	31	2.3	17	2.0	13	1.8	8.5	1.6	6.9	1.4	5.8	ns
		V _{CCI} = 5.0 V ± 0.5 V	2.7	31	2.2	16.5	1.9	12.5	1.6	8.1	1.4	6.4	1.2	5.0	ns
transition		Y output													
	time	V _{CCI} = 1.1 V to 5.5 V	1.0	-	1.0	-	1.0	-	1.0	-	1.0	-	1.0	-	ns
T _{amb} = -4	10 °C to +125 °	°C													
t _{pd}	propagation	A to Y	[1]												
	delay	V _{CCI} = 1.2 V ± 0.1 V	4.0	38	3.6	26	3.4	22	3.1	17	2.9	15	2.7	15	ns
		V _{CCI} = 1.5 V ± 0.1 V	3.5	33	3.0	22	2.8	17.5	2.6	13.5	2.4	11.5	2.2	10.5	ns
		V _{CCI} = 1.8 V ± 0.15 V	3.1	32	2.7	20	2.4	16	2.2	12	2.1	9.7	1.9	9.4	ns
		$V_{CCI} = 2.5 V \pm 0.2 V$	2.8	31	2.4	18.5	2.1	14.5	1.9	9.8	1.7	8.1	1.6	7.1	ns
		V _{CCI} = 3.3 V ± 0.3 V	2.7	31	2.3	18	2.0	14	1.8	9.2	1.6	7.5	1.4	6.3	ns
		V _{CCI} = 5.0 V ± 0.5 V	2.7	31	2.2	17.5	1.9	13.5	1.6	8.8	1.4	6.9	1.2	5.5	ns
t	transition	Y output													
	time	V _{CCI} = 1.1 V to 5.5 V	1.0	-	1.0	-	1.0	-	1.0	-	1.0	-	1.0	-	ns

^[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

Dual supply translating buffer

11.1. Waveform, graphs and test circuit

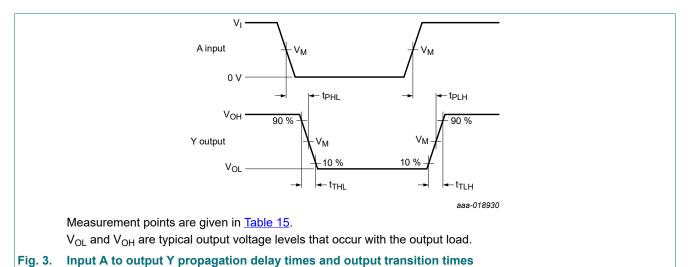
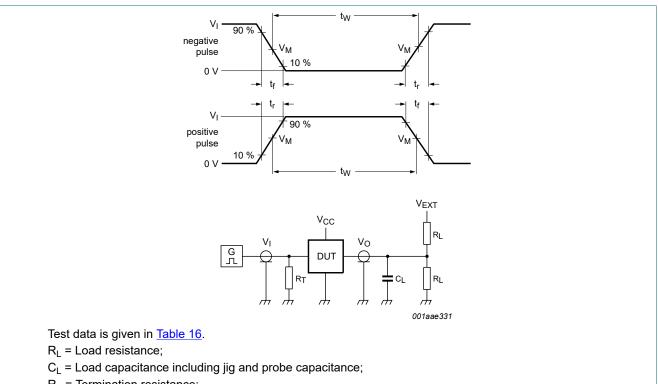


Table 15. Measurement points

Supply voltage		Output	Input		
V _{CCI}	V _{CCO}	V _M	V _M	VI	
0.9 V to 5.5 V	0.9 V to 5.5 V	0.5 x V _{CCO}	0.5 x V _{CCI}	V _{CCI}	



R_T = Termination resistance;

 V_{EXT} = External voltage for measuring switching times.

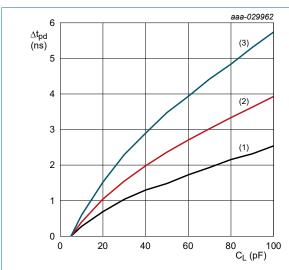
Fig. 4. Test circuit for measuring switching times

Dual supply translating buffer

Table 16. Test data

Supply voltage	Load		Input	V _{EXT}	
V _{CCI} , V _{CCO}	CL	R_L	t _r , t _f	V _I [1]	t _{PLH} , t _{PHL}
0.9 V to 5.5 V	5 pF	10 kΩ	≤3.0 ns	V _{CCI}	GND

[1] V_{CCI} is the supply voltage associated with the control input or input port.



 T_{amb} = -40 °C to +125 °C

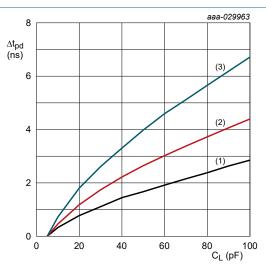
For t_{PLH} and t_{PHL} .

(1) Minimum: $V_{CCO} = 5.5 \text{ V}$

(2) Typical: T_{amb} = 25 °C; V_{CCO} = 5 V

(3) Maximum: V_{CCO} = 4.5 V

Fig. 5. Additional propagation delay versus load capacitance



 T_{amb} = -40 °C to +125 °C

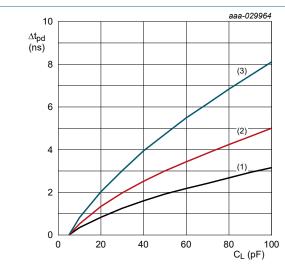
For t_{PLH} and t_{PHL}.

(1) Minimum: $V_{CCO} = 3.6 \text{ V}$

(2) Typical: T_{amb} = 25 °C; V_{CCO} = 3.3 V

(3) Maximum: V_{CCO} = 3 V

Fig. 6. Additional propagation delay versus load capacitance



 T_{amb} = -40 °C to +125 °C

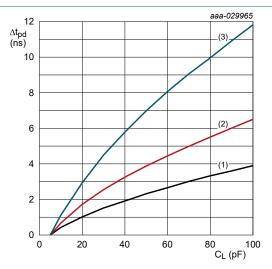
For t_{PLH} and t_{PHL} .

(1) Minimum: $V_{CCO} = 2.7 \text{ V}$

(2) Typical: T_{amb} = 25 °C; V_{CCO} = 2.5 V

(3) Maximum: $V_{CCO} = 2.3 \text{ V}$

Fig. 7. Additional propagation delay versus load capacitance



 T_{amb} = -40 °C to +125 °C

For t_{PLH} and t_{PHL} .

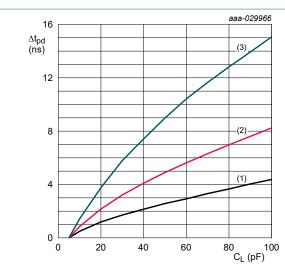
(1) Minimum: $V_{CCO} = 1.95 \text{ V}$

(2) Typical: T_{amb} = 25 °C; V_{CCO} = 1.8 V

(3) Maximum: $V_{CCO} = 1.65 \text{ V}$

Fig. 8. Additional propagation delay versus load capacitance

Dual supply translating buffer



 T_{amb} = -40 °C to +125 °C

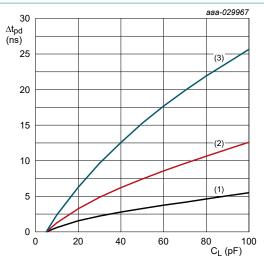
For t_{PLH} and t_{PHL} .

(1) Minimum: $V_{CCO} = 1.6 \text{ V}$

(2) Typical: T_{amb} = 25 °C; V_{CCO} = 1.5 V

(3) Maximum: $V_{CCO} = 1.4 \text{ V}$

Fig. 9. Additional propagation delay versus load capacitance



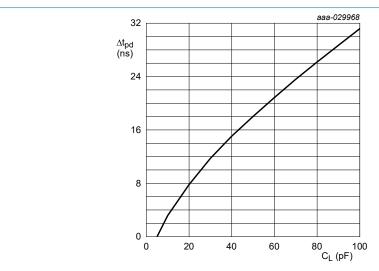
 T_{amb} = -40 °C to +125 °C

For t_{PLH} and t_{PHL}.

(1) Minimum: $V_{CCO} = 1.3 \text{ V}$

(2) Typical: T_{amb} = 25 °C; V_{CCO} = 1.2 V (3) Maximum: V_{CCO} = 1.1 V

Fig. 10. Additional propagation delay versus load capacitance



 T_{amb} = 25 °C For t_{PLH} , t_{PHL} V_{CCO} = 0.9 V

Fig. 11. Additional propagation delay versus load capacitance

Dual supply translating buffer

12. Package outline

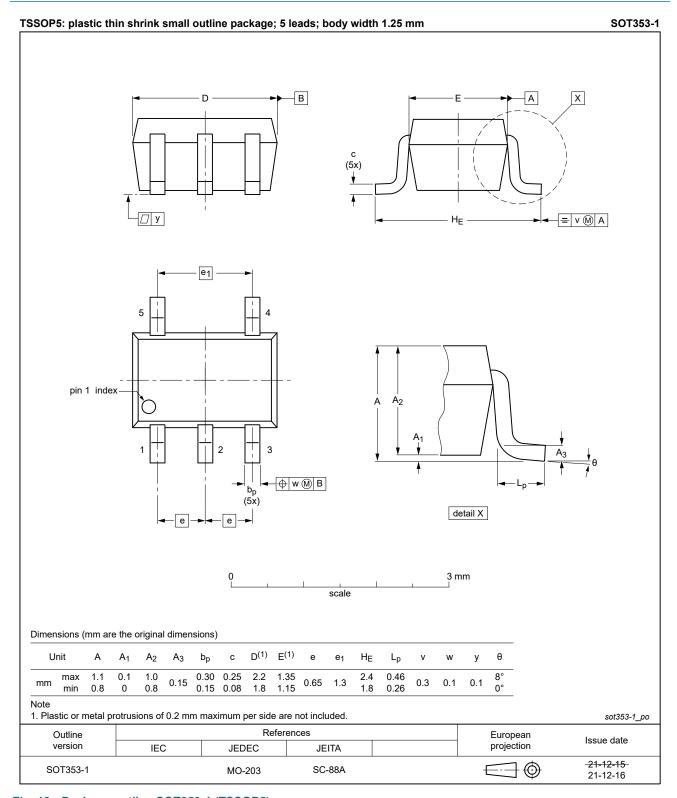


Fig. 12. Package outline SOT353-1 (TSSOP5)

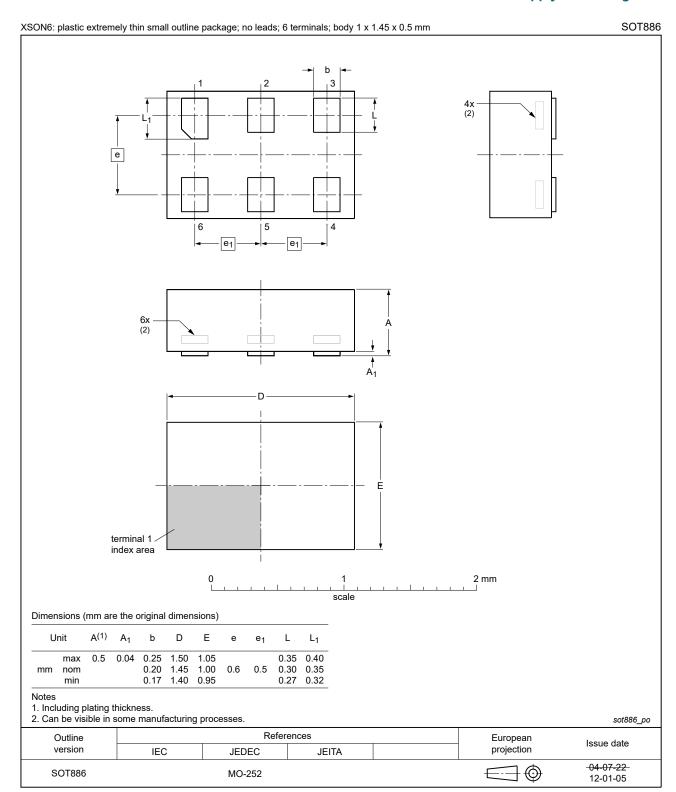


Fig. 13. Package outline SOT886 (XSON6)

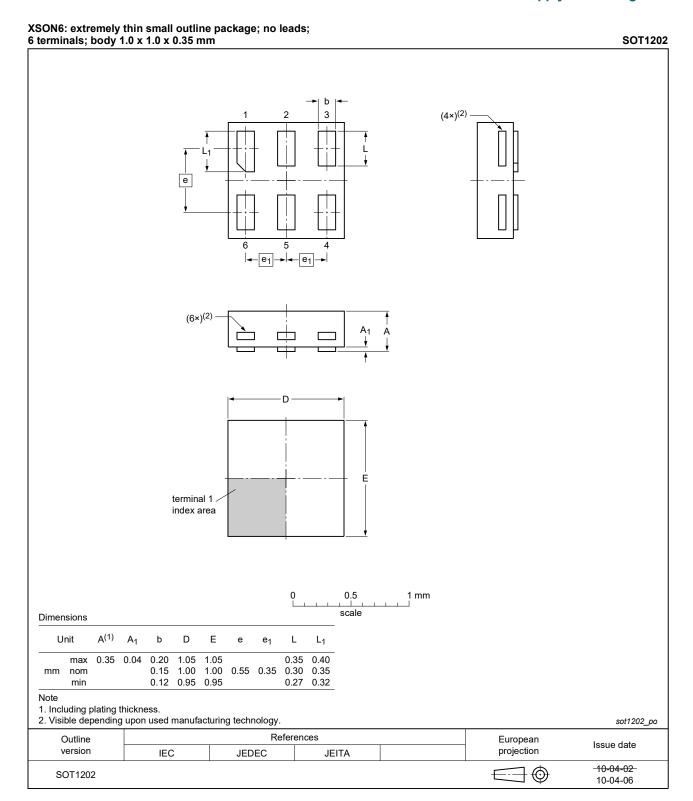


Fig. 14. Package outline SOT1202 (XSON6)

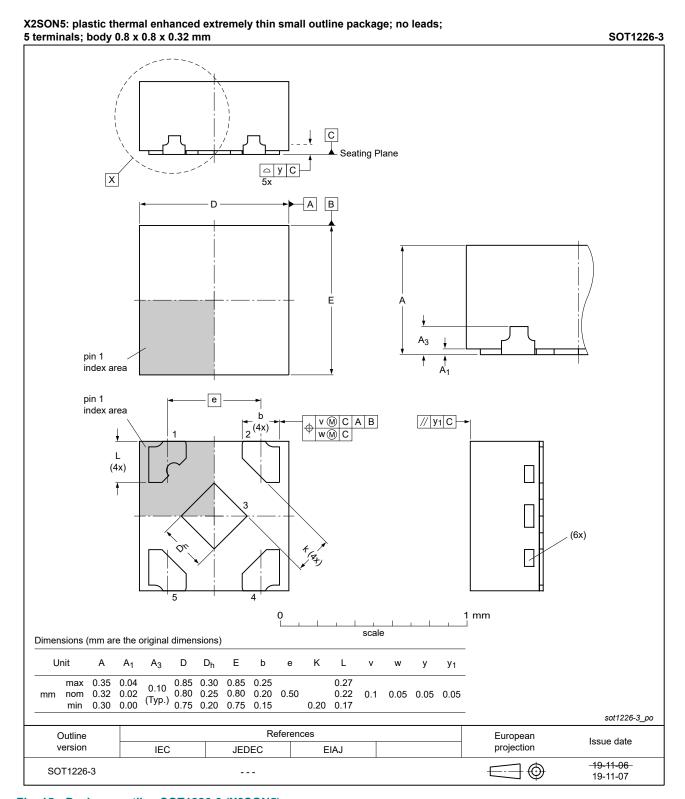


Fig. 15. Package outline SOT1226-3 (X2SON5)

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13. Abbreviations

Table 17. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model

14. Revision history

Table 18. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
AXP1T34 v.1	20231201	Product data sheet	-	-

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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